



## BC846AW-BC848CW

#### NPN SMALL SIGNAL TRANSISTOR IN SOT323

#### **Features**

- Ideally Suited for Automatic Insertion
- Complementary PNP Types: BC856W BC858W
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

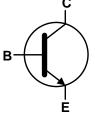
#### **Mechanical Data**

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)



SOT323

Top View



**Device Symbol** 



С

Top View Pin-Out

#### Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel	Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel
BC846AW-7-F	AEC-Q101	K1Q	7	3,000	BC847BWQ-13-F	Automotive	K1R	13	10,000
BC846BW-7-F	AEC-Q101	K1R	7	3,000	BC847CW-7-F	AEC-Q101	K1M	7	3,000
BC846BWQ-7-F	Automotive	K1R	7	3,000	BC847CW-13-F	AEC-Q101	K1M	13	10,000
BC846BW-13-F	AEC-Q101	K1R	13	10,000	BC847CWQ-7-F	Automotive	K1M	7	3,000
BC847AW-7-F	AEC-Q101	K1Q	7	3,000	BC848AW-7-F	AEC-Q101	K1Q	7	3,000
BC847BW-7-F	AEC-Q101	K1R	7	3,000	BC848BW-7-F	AEC-Q101	K1R	7	3,000
BC847BW-13-F	AEC-Q101	K1R	13	10,000	BC848CW-7-F	AEC-Q101	K1M	7	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

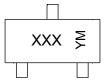
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



XXX = Product Type Marking Code (Please see Ordering Information) YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: E = 2017) M or  $\overline{M}$  = Month (ex: 9 = September)

Date Code Key

Year	2016		2017	2018		2019	2020		2021	2022		2023
Code	D		E	F		G	Н			J		К
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Character	istic	Symbol	Value	Unit
	BC846		80	
Collector-Base Voltage	BC847	V <sub>CBO</sub>	50	V
	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	V <sub>CEO</sub>	45	V
	BC848		30	
	BC846, BC847		6	V
Emitter-Base Voltage	BC848	V <sub>EBO</sub>	5	V
Continuous Collector Current		lc	100	mA
Peak Collector Current		Ісм	200	mA
Peak Base Current		I <sub>BM</sub>	200	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	PD	200	mW
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>0JA</sub>	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C	

## ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

6. For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state. 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



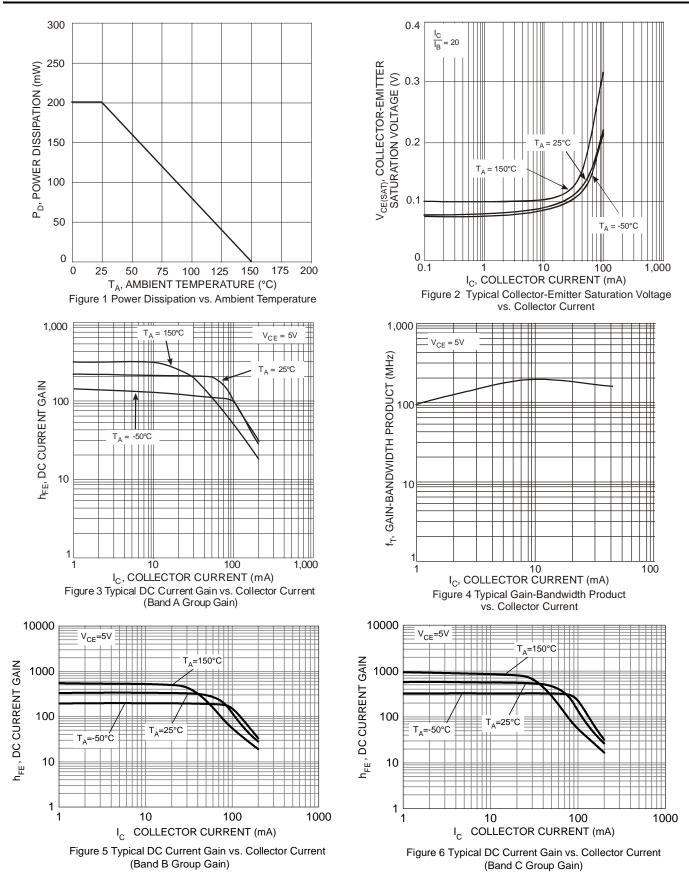
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Char	acteristic			Symbol	Min	Тур	Max	Unit	Test Condition	
		E	3C846		80					
Collector-Base Breakdown Vo	ltage	E	BC847	BV <sub>CBO</sub>	50	—	—	V	I <sub>C</sub> = 100μA	
			3C848		30					
BC846			3C846		65					
Collector-Emitter Breakdown V	/oltage (Note 8)	E	BC847	BV <sub>CEO</sub>	45	—	—	V	$I_{\rm C} = 10 {\rm mA}$	
		E	3C848		30					
Emitter-Base Breakdown Volta		BC84	46, BC847	BVEBO	6			V	I <sub>E</sub> = 100µA	
Enimer-Dase Dreakdown volta	ige	E	3C848	DVEBO	5			v		
			A		110	180	220			
DC Current Gain (Note 8)	Current Gain Gr	roup	В	h <sub>FE</sub>	200	290	450	—	$V_{CE} = 5.0V, I_{C} = 2.0mA$	
			С		420	520	800			
Collector Cutoff Current				I <sub>CBO</sub>	_		20	nA	$V_{CB} = 30V$	
							5	μA	V <sub>CB</sub> = 30V, T <sub>A</sub> = +150°C	
Collector-Emitter Saturation V	oltago (Noto 9)			V <sub>CE(sat)</sub>	_	90	250	mV	$I_{C} = 10mA$ , $I_{B} = 0.5mA$	
	Silage (Note 6)					200	600	IIIV	$I_{C} = 100 \text{mA}, I_{B} = 5.0 \text{mA}$	
Base-Emitter Turn-On Voltage	(Noto 9)				580	660	700	mV	$I_C = 2mA$ , $V_{CE} = 5V$	
Base-Emilier rum-On vollage				V <sub>BE(on)</sub>	_	—	770	mv	$I_{C} = 10 \text{mA}, V_{CE} = 5 \text{V}$	
Base-Emitter Saturation Voltag	na (Nata 9)			V		700		mV	$I_{C} = 10mA, I_{B} = 0.5mA$	
				V <sub>BE(sat)</sub>	_	900		mv	$I_{C} = 100 \text{mA}, I_{B} = 5 \text{mA}$	
Output Capacitance			C <sub>obo</sub>	—	3	4.5	pF	V <sub>CB</sub> = 10V, f = 1.0MHz		
Transition Frequency			f⊤	100	300	_	MHz	$V_{CE} = 5V, I_C = 10mA,$ f = 100MHz		
Noise Figure			NF	_	_	10	dB	$\label{eq:Vce} \begin{split} V_{CE} &= 5V, \ I_C = 200 \mu A \\ R_S &= 2k\Omega, \ f = 1kHz \\ \Delta f &= 200Hz \end{split}$		

Note: 8. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



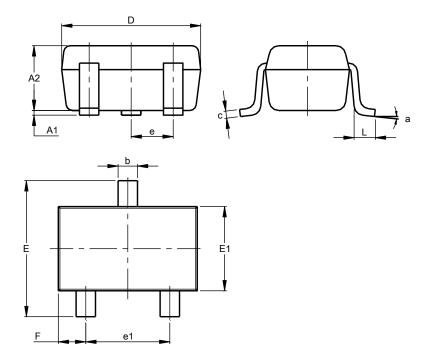
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





# **Package Outline Dimensions**

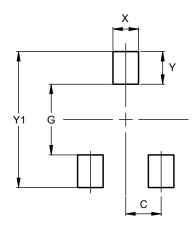
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT323								
Dim	Min	Max	Тур						
A1	0.00	0.10	0.05						
A2	0.90	1.00	0.95						
b	0.25	0.40	0.30						
c	0.10	0.18	0.11						
D	1.80	2.20	2.15						
Е	2.00	2.20	2.10						
E1	1.15	1.35	1.30						
e	C	).650 B	SC						
e1	1.20	1.40	1.30						
F	0.375	0.475	0.425						
L	0.25	0.40	0.30						
а	0°	8°							
All	Dimen	sions	in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500



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